



15A, 45V - 200V Schottky Barrier Surface Mount Rectifier

FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- Guard ring for overvoltage protection
- High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

MECHANICAL DATA

- Case: TO-263AB (D²PAK)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: As marked
- Weight: 1.37g (approximately)

KEY PARAMETERS			
PARAMETER	VALUE	UNIT	
I _F	15	Α	
V_{RRM}	45 - 200	V	
I _{FSM}	150	Α	
T_{JMAX}	150	°C	
Package	TO-263AB (D ² PAK)		
Configuration	Dual dies		

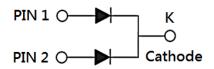








TO-263AB (D²PAK)



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)							
		MBRS	MBRS	MBRS	MBRS	MBRS	
PARAMETER	SYMBOL	1545	1560	15100	15150	15200	UNIT
		CT-Y	CT-Y	CT-Y	CT-Y	CT-Y	
Marking code on the device		MBRS 1545CT	MBRS 1560CT	MBRS 15100CT	MBRS 15150CT	MBRS 15200CT	
Repetitive peak reverse voltage	V_{RRM}	45	60	100	150	200	V
Reverse voltage, total rms value	$V_{R(RMS)}$	31	42	70	105	140	V
Forward current	I _F	l _F 15			Α		
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}	150				Α	
Peak repetitive reverse surge current ⁽¹⁾	I_{RRM}	1 0.5			Α		
Peak repetitive forward current (Rated V _R , Square wave, 20KHz)	I _{FRM}	15			А		
Critical rate of rise of off-state voltage	dv/dt	dv/dt 10,000			V/µs		
Junction temperature	T_J	-55 to +150			°C		
Storage temperature	T _{STG}	-55 to +150			°C		

Notes:

1. $tp = 2.0\mu s$, 1.0KHz

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THERMAL PERFORMANCE				
PARAMETER	SYMBOL	TYP	UNIT	
Junction-to-ambient thermal resistance	R _{OJA}	50	°C/W	
Junction-to-case thermal resistance	R _{eJC}	2	°C/W	

PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
	MBRS1545CT-Y	I _F = 7.5A, T _J = 25°C		-	-	V
	MBRS1560CT-Y			-	0.75	V
	MBRS15100CT-Y			-	0.92	V
	MBRS15150CT-Y MBRS15200CT-Y			-	0.95	V
	MBRS1545CT-Y			-	0.84	V
	MBRS1560CT-Y			-	-	V
	MBRS15100CT-Y	$I_F = 15.0A, T_J = 25^{\circ}C$	V _F	-	-	V
Forward voltage per	MBRS15150CT-Y MBRS15200CT-Y			-	-	V
diode ⁽¹⁾	MBRS1545CT-Y		V F	-	0.57	V
	MBRS1560CT-Y	I _F = 7.5A, T _J = 125°C		-	0.65	V
	MBRS15100CT-Y			-	0.82	V
	MBRS15150CT-Y MBRS15200CT-Y			-	0.92	V
	MBRS1545CT-Y			-	0.72	٧
	MBRS1560CT-Y	I _F = 15.0A, T _J = 125°C		-	-	V
	MBRS15100CT-Y			-	-	V
	MBRS15150CT-Y MBRS15200CT-Y			-	-	V
Reverse current @ rated V _R per diode ⁽²⁾	MBRS1545CT-Y MBRS1560CT-Y MBRS15100CT-Y MBRS15150CT-Y MBRS15200CT-Y	T _J = 25°C		-	100	μA
	MBRS1545CT-Y		I _R	-	15	mA
	MBRS1560CT-Y	T 40700		-	10	mA
	MBRS15100CT-Y MBRS15150CT-Y MBRS15200CT-Y			-	5	mA

Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION			
ORDERING CODE ⁽¹⁾	PACKAGE	PACKING	
MBRS15xCT-Y	TO-263AB (D ² PAK)	800 / Tape & Reel	

Notes

1. "x" defines voltage from 45V(MBRS1545CT-Y) to 200V(MBRS15200CT-Y)

Fig.2 Typical Junction Capacitance



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.1 Forward Current Derating Curve

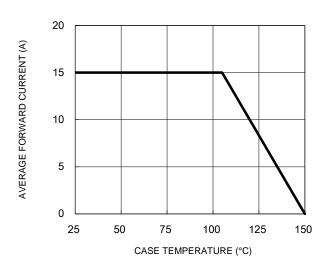


Fig.3 Typical Reverse Characteristics

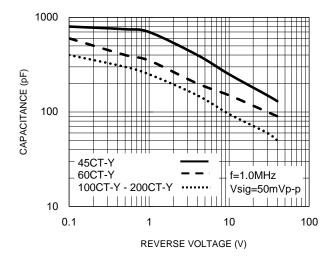
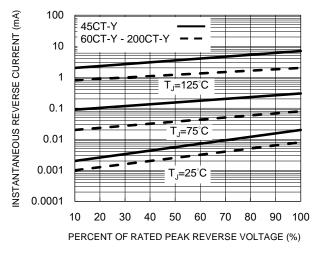


Fig.4 Typical Forward Characteristics



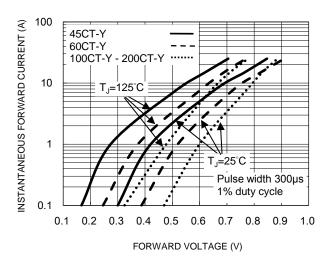
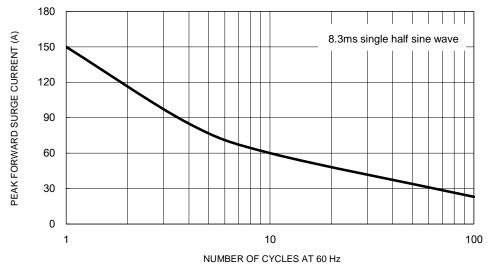


Fig.5 Maximum Non-Repetitive Forward Surge Current

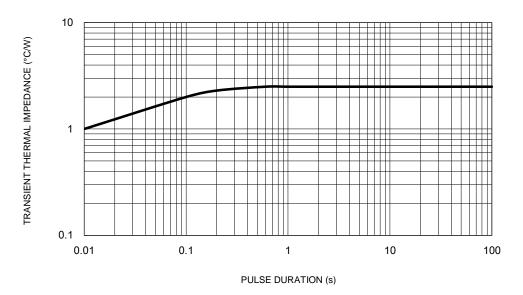


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CHARACTERISTICS CURVES

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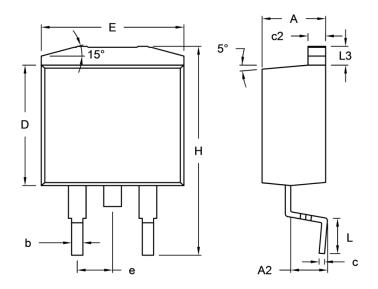
Fig.6 Typical Transient Thermal Impedance





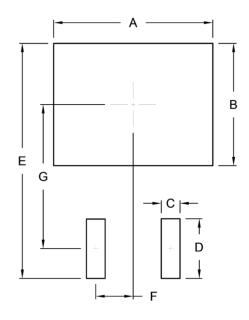
PACKAGE OUTLINE DIMENSIONS

TO-263AB (D²PAK)



DIM.	Unit (mm)		Unit ((inch)
DIW.	Min.	Max.	Min.	Max.
Α	4.44	4.70	0.175	0.185
A2	2.03	2.79	0.080	0.110
b	0.68	0.94	0.027	0.037
С	0.36	0.53	0.014	0.021
c2	1.14	1.40	0.045	0.055
D	8.25	9.25	0.325	0.364
Е	-	10.50	-	0.413
е	2.41	2.67	0.095	0.105
Н	14.60	15.88	0.575	0.625
L	2.29	2.79	0.090	0.110
L3	1.14	1.40	0.045	0.055

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
Α	10.80	0.425
В	8.30	0.327
С	1.27	0.050
D	4.05	0.159
E	15.95	0.628
F	2.54	0.100
G	9.775	0.385

MARKING DIAGRAM



P/N = Marking Code G = Green Compound

YWW = Date Code = Factory Code



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